

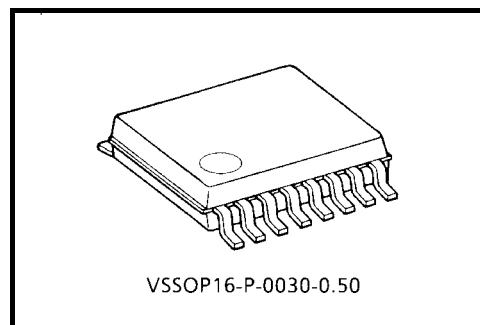
TC7MP01FK

Low-Voltage Triple Gate(6-input AND + 4-input OR + inverter)

The TC7MP01FK is a high-performance CMOS triple gate (6-input AND + 4-input OR + inverter). Designed for use in 1.8 V, 2.5 V, or 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6V.

All inputs are equipped with protection circuits against static discharge.

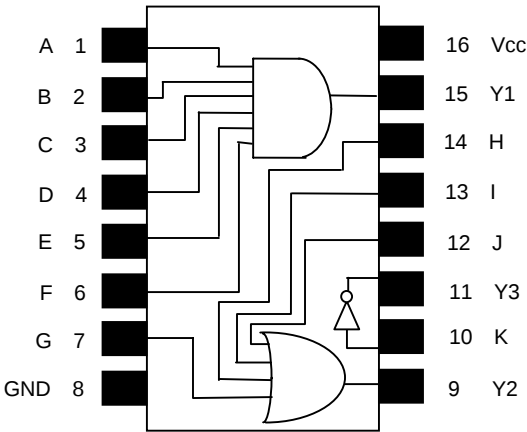


Weight : 0.03 g (typ.)

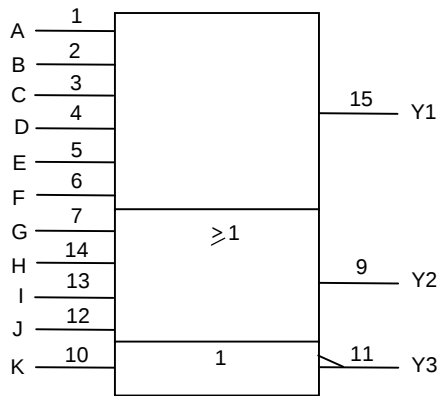
Features

- Low-voltage operation : $V_{CC} = 1.65$ to $3.6V$
- Quiescent supply current : $I_{CC} = 2 \mu A$ (max) ($V_{CC}=3.6V$)
- High-speed operation : 6 input AND
 - $t_{pd}=3.7ns$ (max) ($V_{CC}=3.3 \pm 0.3V$)
 - $t_{pd}=5.5ns$ (max) ($V_{CC}=2.5 \pm 0.2V$)
 - $t_{pd}=11.0ns$ (max) ($V_{CC}=1.8 \pm 0.15V$)
- 4 input OR
 - $t_{pd}=3.5ns$ (max) ($V_{CC}=3.3 \pm 0.3V$)
 - $t_{pd}=5.0ns$ (max) ($V_{CC}=2.5 \pm 0.2V$)
 - $t_{pd}=10.0ns$ (max) ($V_{CC}=1.8 \pm 0.15V$)
- INV.
 - $t_{pd}=3.8ns$ (max) ($V_{CC}=3.3 \pm 0.3V$)
 - $t_{pd}=5.2ns$ (max) ($V_{CC}=2.5 \pm 0.2V$)
 - $t_{pd}=9.5ns$ (max) ($V_{CC}=1.8 \pm 0.15V$)
- Output current : $I_{OH}/I_{OL} = \pm 12mA$ (min) ($V_{CC}=3.0V$)
: $I_{OH}/I_{OL} = \pm 9mA$ (min) ($V_{CC} = 2.3V$)
: $I_{OH}/I_{OL} = \pm 2mA$ (min) ($V_{CC} = 1.65V$)
- Latch-up performance : $\pm 300mA$
- ESD performance : Machine model $> \pm 200V$
: Human body model $> \pm 2000V$
- Ultra-small package : VSSOP (US16)
- Power-down protection provided on all inputs and outputs.

Pin Assignment (top view)



IEC Logic Symbol



Truth Table (AND Logic)

A	B	C	D	E	F	Y1
L	x	x	x	x	x	L
x	L	x	x	x	x	L
x	x	L	x	x	x	L
x	x	x	L	x	x	L
x	x	x	x	L	x	L
x	x	x	x	x	L	L
H	H	H	H	H	H	H

Truth Table (OR Logic)

G	H	I	J	Y2
H	x	x	x	H
x	H	x	x	H
x	x	H	x	H
x	x	x	H	H
L	L	L	L	L

Truth Table (INV. Logic)

K	Y3
L	H
H	L

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	- 0.5 to 4.6	V
DC input voltage	V _{IN}	- 0.5 to 4.6	V
DC output voltage	V _{OUT}	- 0.5 to 4.6 (Note 1)	V
		- 0.5 to V _{CC} +0.5 (Note 2)	
Input diode current	I _{IK}	- 50	mA
Output diode current	I _{OK}	± 50 (Note 3)	mA
DC output current	I _{OUT}	± 50	mA
DC V _{CC} /ground current	I _{CC} /I _{GND}	± 100	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	- 65 to 150	

(Note 1) V_{CC} = 0V

(Note 2) High or low state.

(Note 3) V_{OUT} < GND , V_{OUT} > V_{CC}

Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.65 to 3.6	V
		1.2 to 3.6(Note 4)	
DC input voltage	V _{IN}	- 0.3 to 3.6	V
DC output voltage	V _{OUT}	0 to 3.6 (Note 5)	V
		0 to V _{CC} (Note 6)	
Output current	I _{OH} /I _{OL}	± 12 (Note 7)	mA
		± 9 (Note 8)	
		± 2 (Note 9)	
Operating Temperature	T _{opr}	- 40 to 85	
Input rise and fall time	dt / dv	0 to 10 (Note 10)	ns/V

(Note 4) Data retention only

(Note 5) V_{CC} = 0V

(Note 6) High or low state

(Note 7) V_{CC} = 3.0 to 3.6V

(Note 8) V_{CC} = 2.3 to 2.7V

(Note 9) V_{CC} = 1.65 to 1.95V

(Note 10) V_{IN}=0.8 to 2.0V,V_{CC}=3.0V

Electrical Characteristics
DC Characteristics (Ta=-40 to 85 , 2.7V < Vcc 3.6V)

Characteristics		Symbol	Test condition		Vcc(V)	Min	Max	Unit
Input Voltage	H-level	V _{IH}	-		2.7 to 3.6	2.0	-	V
	L-level	V _{IL}	-		2.7 to 3.6	-	0.8	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100uA	2.7 to 3.6	Vcc-0.2	-	V
				I _{OH} = -6mA	2.7	2.2	-	
				I _{OH} = -9mA	3.0	2.4	-	
				I _{OH} = -12mA	3.0	2.2	-	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100uA	2.7 to 3.6	-	0.2	
				I _{OL} = 6mA	2.7	-	0.4	
				I _{OL} = 9mA	3.0	-	0.4	
				I _{OL} = 12mA	3.0	-	0.55	
Input leakage current		I _{IN}	V _{IN} =0 to 3.6V		2.7 to 3.6	-	± 2.0	μ A
Power-off leakage current		I _{OFF}	V _{IN} ,V _{OUT} =0 to 3.6V		0	-	2.0	μ A
Quiescent supply current		I _{CC}	V _{IN} =V _{CC} or GND		2.7 to 3.6	-	2.0	μ A
		Δ I _{CC}	V _{IN} =V _{CC} -0.6V (per input)		2.7 to 3.6	-	750	μ A

DC Characteristics (Ta=-40 to 85 , 2.3V Vcc 2.7V)

Characteristics		Symbol	Test condition		Vcc(V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	-		2.3 to 2.7	1.6	-	V
	L-level	V _{IL}	-		2.3 to 2.7	-	0.7	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} =-100uA	2.3 to 2.7	Vcc-0.2	-	V
				I _{OH} = -3mA	2.3	2.0	-	
				I _{OH} = -6mA	2.3	1.8	-	
				I _{OH} = -9mA	2.3	1.7	-	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100uA	2.3 to 2.7	-	0.2	
				I _{OL} = 6mA	2.3	-	0.4	
				I _{OL} = 9mA	2.3	-	0.6	
Input leakage current			V _{IN} =0 to 3.6V		2.3 to 2.7	-	± 2.0	μ A
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} =0 to 3.6V		0	-	2.0	μ A
Quiescent supply current		I _{CC}	V _{IN} =V _{CC} or GND		2.3 to 2.7	-	2.0	μ A

DC Characteristics (Ta=-40 to 85 , 1.65V Vcc < 2.3V)

Characteristics		Symbol	Test condition		Vcc(V)	Min	Max	Unit
Input voltage	H-Level	V _{IH}	-		1.65 to 2.3	0.7 × Vcc	-	V
	L-Level	V _{IL}	-		1.65 to 2.3	-	0.13 × Vcc	
Output voltage	H-Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} =-100uA	1.65	Vcc-0.2	-	V
				I _{OH} =-2mA	1.65	1.3	-	
	L-Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} =2mA	1.65	-	0.2	
Input leakage current		I _{IN}	V _{IN} =0 to 3.6V		1.65	-	± 2.0	μ A
Power-off leakage current		I _{OFF}	V _{IN} ,V _{OUT} =0 to 3.6V		0	-	2.0	μ A
Quiescent supply current		I _{CC}	V _{IN} =V _{CC} or GND		1.65	-	2.0	μ A

AC Characteristics (Ta=-40 to 85 , Input: tr=tf=2.0ns, CL=30pF, RL=500Ω)

Characteristics	Symbol	Test condition		Vcc(V)	Min	Max	Unit
Propagation delay time	tpLH tpHL	6 input AND	Figure 1, Figure 2	1.8 ± 0.15	1.0	11.0	ns
				2.5 ± 0.2	0.8	5.5	
				3.3 ± 0.3	0.6	3.7	
		4 input OR		1.8 ± 0.15	1.0	10.0	
				2.5 ± 0.2	0.8	5.0	
				3.3 ± 0.3	0.6	3.5	
		INV.		1.8 ± 0.15	1.0	9.5	
				2.5 ± 0.2	0.8	5.2	
				3.3 ± 0.3	0.6	3.8	
Output to output skew	tosLH tosHL	(Note 11)		1.8 ± 0.15	-	0.5	ns
				2.5 ± 0.2	-	0.5	
				3.3 ± 0.3	-	0.5	

For CL=50pF, add approximately 300ps to the AC maximum specification.

Note 11: Parameter guaranteed by design.

$$(tosLH = |t_{pLHm} - t_{pLHn}|, \quad tosHL = |t_{pHLm} - t_{pHLn}|)$$

Capacitive Characteristics(Ta=25)

Characteristics	Symbol	Test Condition		Vcc(V)	Typ.	Unit
Input Capacitance	C _{IN}	-		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	6 input AND	fin=10MH z Table 1、(Note12)	1.8, 2.5, 3.3	18	pF
		4 input OR		1.8, 2.5, 3.3	17	
		INV.		1.8, 2.5, 3.3	14	

Note12: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot V_{IN} + I_{CC}/3 \text{ (per gate)}$$

Table1 C_{PD} Test Condition

Function	Pin															
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
6 input AND	P	H	H	H	H	H	X	G	O	X	O	X	X	X	C	V
4 input OR	X	X	X	X	X	X	P	G	C	X	O	L	L	L	O	V
INV.	X	X	X	X	X	X	X	G	O	P	C	X	X	X	O	V

- Symbol explanation -

V=V_{CC}(+3.3V)

G=GND(0V)

H=Logic1(V_{CC})

L=Logic0(GND)

X=Don't care(Fixed to V_{CC} or GND)

O=Open

C=Connect a condenser(30pF) between output terminal and GND.

P=Input pulse with 50% duty cycle.

AC Test Circuit

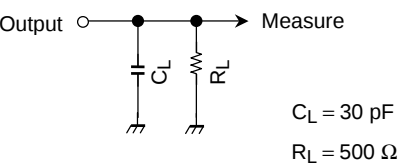
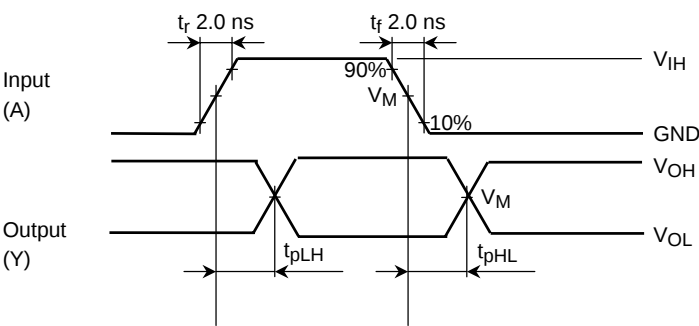


Figure 1

AC Waveform



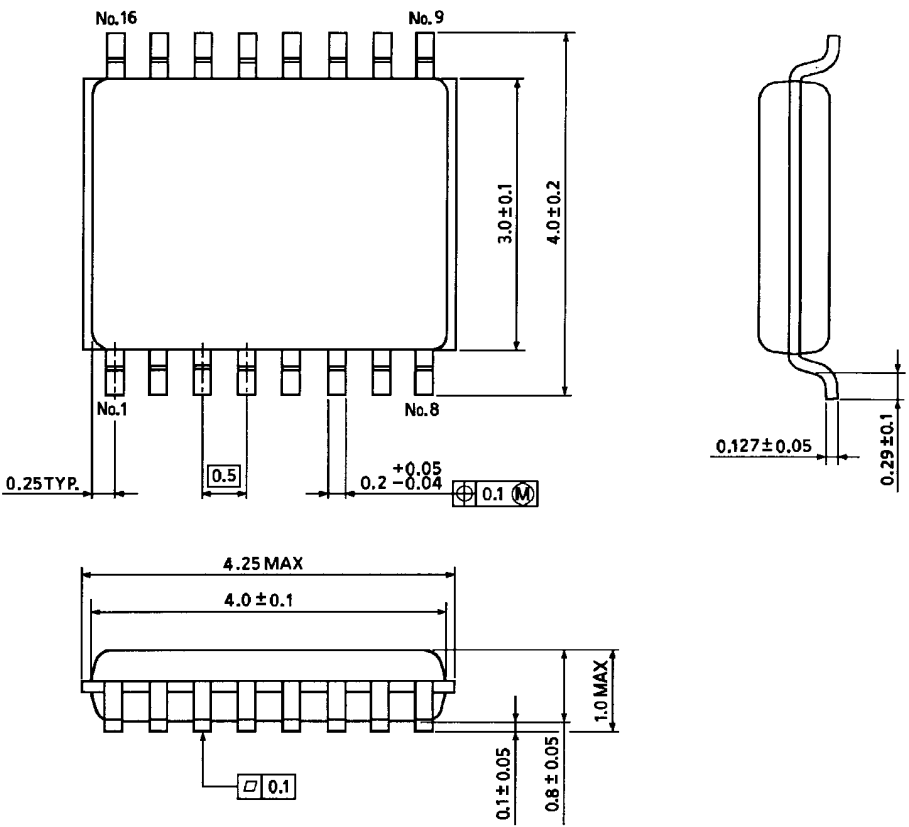
Symbol	Vcc		
	3.3 ± 0.3V	2.5 ± 0.2V	1.8 ± 0.15V
V_{IH}	2.7V	Vcc	Vcc
V_M	1.5V	Vcc/2	Vcc/2

Figure 2 t_{pLH} , t_{pHL}

Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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